L Number	Hits	Search Text	DB	Time stamp
1	2	("5500750").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 17:35
5	1186	(349/113).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 17:43
6	3834	349/$.ccls. and density	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 18:32
7	80	349/$.ccls. and density and permeation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 18:44
8	1		USPAT	2004/01/22 18:34
9	1		USPAT	2004/01/22 18:34
10	1		USPAT	2004/01/22 18:34
11	1		USPAT	2004/01/22 18:35
12	1		USPAT	2004/01/22 18:35
13	1		USPAT	2004/01/22 18:35
14	1		USPAT	2004/01/22 18:35
15	1		USPAT	2004/01/22 18:36
16	1		USPAT	2004/01/22 18:36
17	1		USPAT	2004/01/22 18:36
18	28	349/$.ccls. and (density with barrier)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 18:45
19	22	(349/$.ccls. and (density with barrier)) not (349/$.ccls. and density and permeation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 18:47
20	79	349/$.ccls. and (coating with density)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 18:47
21	73	(349/$.ccls. and (coating with density)) not (349/$.ccls. and density and permeation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 18:54
22	34	(((silicon adj (nitride oxide)) with density) ((aluminum adj oxide) with density)) and 349/$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 19:00

23	5916	(((silicon adj (nitride oxide)) with density) ((aluminum adj oxide) with density))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 19:00
24	350	(((silicon adj (nitride oxide)) with density) ((aluminum adj oxide) with density)) and "liquid crystal"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 19:06
25	316	((((silicon adj (nitride oxide)) with density) ((aluminum adj oxide) with density)) and "liquid crystal") not ((349/$.ccls. and density and permeation) (349/$.ccls. and (density with barrier)) (349/$.ccls. and (coating with density)) ((((silicon adj (nitride oxide)) with density) ((aluminum adj oxide) with density)) and 349/$.ccls.))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 19:04
27	204	(((silicon adj (nitride oxide)) with density) ((aluminum adj oxide) with density)) and (g adj3 (cm cc))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 19:09
28	119	(((silicon adj (nitride oxide)) with (g adj3 (cm cc))) ((aluminum adj oxide) with (g adj3 (cm cc))))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 19:39
29	61	(((silicon adj (oxide)) with (g adj3 (cm cc))) ((aluminum adj oxide) with (g adj3 (cm cc))))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 19:39
30	421	(349/158.ccls. 349/113.ccls.) and (sio sin alo "silicon nitride" "silicon oxide" "aluminum oxide")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 19:47
31	0	(polycorbonate with substrate) and 349/$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 20:05
32	400	(polycarbonate with substrate) and 349/$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 20:06